General Description

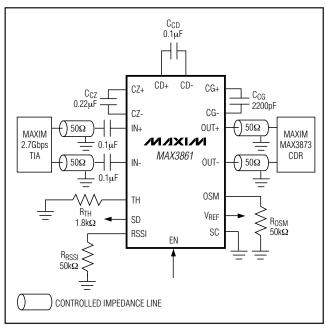
The MAX3861 is a low-power amplifier with automatic gain control (AGC), designed for WDM transmission systems employing optical amplifiers and requiring a vertical threshold adjustment after the post amp. Operating from a single 3.3V supply, this AGC amplifier linearly amplifies/attenuates the input signal while maintaining a fixed output-voltage swing at data rates up to 2.7Gbps. The input and output are on-chip terminated to match 50Ω interfaces.

This amplifier has a small-signal bandwidth of 3.4GHz and an input-referred noise of 0.26mV_{RMS}. Over an input signal range of 6mV_{P-P} to 1200mV_{P-P} (46dB), the MAX3861 delivers a constant output amplitude adjustable from 400mV_{P-P} to 920mV_{P-P}. Variation in output swing is controlled within 0.2dB over a 16dB input range. The MAX3861 provides a received-signalstrength indicator (RSSI) that is linear, within 2.5%, for input signal levels up to 100mV_{P-P} and an input signal detect (SD) with programmable threshold.

Applications

OC-48/STM-16 Transmission Systems WDM Optical Receivers Long-Reach Optical Receivers Continuous Rate Receivers

Typical Application Circuit



Features

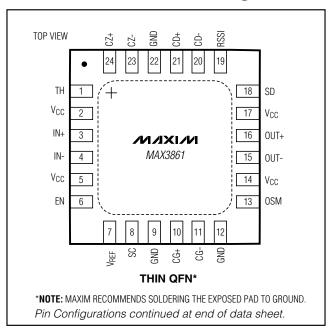
- ♦ Single 3.3V Power Supply
- ♦ 72mA Supply Current
- ♦ 3.4GHz Small-Signal Bandwidth
- ♦ 0.26mV_{RMS} Input-Referred Noise
- ♦ 6mV_{P-P} to 1200mV_{P-P} Input Range (46dB)
- ♦ Input Signal Detect with Programmable Threshold
- ♦ RSSI (Linear Up to 100mVp-p)
- ♦ Adjustable Output Amplitude
- ♦ 0.2dB Output Voltage Variation (Over 16dB Input Signal Variation)

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	PACKAGE CODE
MAX3861ETG+	-40°C to +85°C	24 Thin QFN-EP*	T2444-3
MAX3861EGG	-40°C to +85°C	24 QFN-EP*	G2444-1

⁺Denotes lead-free package.

Pin Configurations



MIXIM

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

^{*}EP = Exposed pad.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage0.5V to +4.0V Voltage at IN+, IN(V _{CC} - 1.5V) to (V _{CC} + 0.5V) Voltage at CZ+, CZ-, CG+,	CML Output Current at OUT+, OUT25mA Continuous Power Dissipation TA = +85°C (24-Pin QFN and 24-Pin Thin QFN)
CG-, CD+, CD(V _{CC} - 3.5V) to (V _{CC} + 0.5V) Voltage at SC, SD, EN, TH, OSM, V _{REF} , RSSI0.5V to (V _{CC} + 0.5V) CML Input Current at IN+, IN25mA	(derate 20.8mW/°C above +85°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +3.0 \text{V to } +3.6 \text{V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}. \text{ Typical values are at } V_{CC} = +3.3 \text{V and } T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$ (Note 1)

PARAMETER	SYMBOL CONDITIONS		MIN	TYP	MAX	UNITS		
		RSSI and SD enabled	At minimum gain		72	86		
Supply Current	Icc	(Notes 2, 3)	At maximum gain		94	112	m _A	
Supply Current	100	RSSI and SD disabled	At minimum gain		57	69		
		(Notes 2, 3)	At maximum gain		78	94		
Power-Supply Noise Rejection	PSNR	$V_{NOISE} = 100 \text{mV}_{P-P},$ $f_{NOISE} \le 10 \text{MHz},$	V _{IN} = 1000mV _{P-P}		35		dB	
Tower Supply Noise Hojection	1 01111	V _{SC} = 2V (Note 4)	$V_{IN} = 10 \text{mV}_{P-P}$		25		42	
Input Data Rate					2.7		Gbps	
Input Resistance	R _{IN}	Single-ended to V _{CC}		40	50	60	Ω	
Input Deturn Lees		≤2.7GHz			21		٩D	
Input Return Loss		2.7GHz to 4.0GHz			15		dB	
Input Common-Mode Level				V _{CC} - 0.3		Vcc	V	
Input-Referred Noise		Up to 6GHz at max gain,	$C_{CZ} = 0.1 \mu F$		0.26	0.35	mV _{RMS}	
Input Voltage Range	VIN	Differential	•	6		1200	mV _{P-P}	
Maximum Differential Input		0.0 < 1 = = = = = = = = = = = = = = = = = =	$V_{SC} = 0$		700		\/	
Voltage for Linear Operation		0.9 ≤ linearity ≤ 1.1	V _{SC} = 2V		650		mV _{P-P}	
Output Resistance	Rout	Single-ended to V _{CC}		40	50	60	Ω	
Output Beturn Lees		≤2.7GHz		16		dD		
Output Return Loss		2.7GHz to 4.0GHz	11			dB		
Outrout Common Made Lavel		D. 500 to V	V _{SC} = 0		V _{CC} - 0.13		V	
Output Common-Mode Level		$R_L = 50\Omega$ to V_{CC}	V _{SC} = 2V		V _{CC} - 0.28			
		V _{SC} = 0,	$6mV_{P-P} \le V_{IN} \le 700mV_{P-P}$		±3	±14		
Maximum Differential Output		$R_L = 50\Omega$ to V_{CC} (Note 5)	700mV _{P-P} ≤ V _{IN} ≤ 1200mV _{P-P}		±8			
Offset		V _{SC} = 2V,	$6mV_{P-P} \le V_{IN} \le 700mV_{P-P}$		±5.5	±28	mV	
		$R_L = 50\Omega$ to V_{CC} (Note 5)	700mV _{P-P} ≤ V _{IN} ≤ 1200mV _{P-P}		±11			

2 /VIXI/VI

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CC} = +3.0 \text{V to } +3.6 \text{V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}. \text{ Typical values are at } V_{CC} = +3.3 \text{V} \text{ and } T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$ (Note 1)

PARAMETER	SYMBOL	CO	NDITIO	ONS	MIN	TYP	MAX	UNITS	
Differential Output Appolitude	\/	$R_L = 50\Omega$ to V_{CC}		$V_{SC} = 0$	300	400	500	ma\/	
Differential Output Amplitude	Vout	(Note 6)		V _{SC} = 2V	760	760 920 10		mV _{P-P}	
Output Amplitude Variation	ΔV _{OUT}	V _{IN} ≥ 6mV _{P-P} , R _L =	50Ω t	o V _{CC} (Notes 6, 7)		0.2	1.0	dB	
0 110: 15 1:11	DW	(1)		At minimum gain	2.5	3.4	5.5	011	
Small Signal Bandwidth	BW	(Note 3)		At maximum gain	2.2	2.9	4.3	GHz	
Low-Frequency Cutoff		$C_{CZ} = 0.1 \mu F$				7.6	13	kHz	
Deterministic Jitter		(Note 8)				15	50	psp-p	
Output Cianal Manitar Valtage	\/	R _{OSM} ≥ 2kΩ	V	OUT = 920mV _{P-P}		2.0		V	
Output Signal Monitor Voltage	Vosm	(Note 6)	V	$OUT = 400 \text{mV}_{P-P}$		0.9		V	
Output Signal Monitor Linearity		$0V \le V_{SC} \le 2V$ (Note	e 6)			1.0		%	
SC Input Range		(Note 9)			0		2.0	V	
AGC Loop Constant		Without external ca V _{SC} = 0 (Note 10)	pacito	r C _{CG} ,		16		μs	
RSSI Output Voltage	RSSI	$R_{RSSI} \ge 2k\Omega$, $V_{SC} = 0$		V _{IN} = 2mV _{P-P}		55		mV	
11331 Output Voltage	11001	(Note 6)		$V_{IN} = 100 \text{mV}_{P-P}$		1800		1114	
RSSI Linearity		$2mV_{P-P} \le V_{IN} \le 100mV_{P-P} \text{ (Note 14)}$ $6mV_{P-P} \le V_{IN} \le 100mV_{P-P}$			±2.5	±12	- %		
nooi Linearity					±2.5	±8			
Minimum SD Assert Input							2	mV _{P-P}	
Maximum SD Assert Input					100			mV _{P-P}	
SD Assert Time					10	70		μs	
SD Deassert Time		CG+ and CG- are of	pen (I	Note 11)	10	44		μs	
SD Accuracy		(Note 12)				±10		%	
SD Hysteresis		$10\text{mV}_{P-P} \le V_{IN} \le 100\text{mV}_{P-P}$.P	2.8	4.5	6.3	dB	
3D Hysteresis		$2mV_{P-P} \le V_{IN} \le 10n$	nV _{P-P}	(Note 13)		4.5		иь	
SD Output High Voltage		Sourcing 20µA curr	ent		2.4			V	
SD Output Low Voltage		Sinking 2mA currer	nt				0.44	V	
EN Input Low Voltage	VIL						0.8	V	
EN Input High Voltage VIH					2.0			V	
EN Input Low Current	IլL	V _{IL} = 0				10	μΑ		
EN Input High Current I _{IH} V _{IH} = 2.0V				10	μΑ				
V _{REF} Output Voltage		$R_{VREF} \ge 40 k\Omega$				2.0		V	

- **Note 1:** Electrical characteristics are measured or characterized using a 2²³ 1PRBS at 2.7Gbps with input edge speeds ≤200ps, unless otherwise noted. All AC specifications are guaranteed by design and characterization, unless otherwise noted.
- **Note 2:** Supply current measurement is taken with AC-coupled inputs and excludes output currents into 50Ω loads.
- **Note 3:** Minimum gain is defined as $V_{IN} = 1200 \text{mVp-p}$ and $V_{OUT} = 400 \text{mVp-p}$. Maximum gain is defined as $V_{IN} = 6 \text{mVp-p}$, and $V_{OUT} = 920 \text{mVp-p}$. Reference gain is measured at 100MHz.
- **Note 4:** Power-supply noise rejection is characterized with a 2.7Gbps 1100 pattern on the input. It is calculated by the equation PSNR = $20\log(\Delta V_{CC} / (\Delta V_{OUT}))$, where ΔV_{OUT} is the change in differential output voltage because of power-supply noise. See the Power-Supply Noise Rejection vs. Frequency graph in the *Typical Operating Characteristics*.



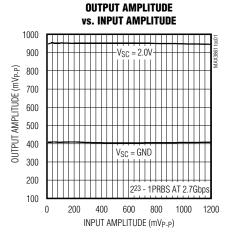
ELECTRICAL CHARACTERISTICS (continued)

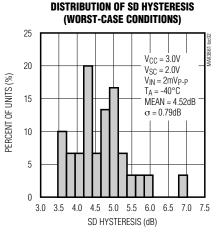
 $(V_{CC} = +3.0 \text{V to } +3.6 \text{V}, T_A = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}. \text{ Typical values are at } V_{CC} = +3.3 \text{V} \text{ and } T_A = +25 ^{\circ}\text{C}, \text{ unless otherwise noted.})$ (Note 1)

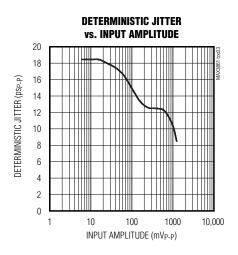
- Note 5: See the Distribution of Differential Output Offset (Worst-Case Conditions) graph in the Typical Operating Characteristics.
- **Note 6:** Characterized with a 675Mbps 1-0 pattern.
- lote 7: Measurements are taken over an input signal range of 16dB.
- **Note 8:** Deterministic jitter is defined as the arithmetic sum of PWD (pulse-width distortion) and PDJ (pattern-dependent jitter). Deterministic jitter is the difference between total jitter and random jitter, with system jitter calibrated out. It is measured with a 2⁷ 1PRBS, and 80CIDs with DC-coupled outputs.
- **Note 9:** The typical input resistance of the SC pin is $40k\Omega$.
- Note 10: AGC loop time constant is measured with a 20dB change in the input and V_{SC} held constant. With an external capacitor C_{CG} of 0.022µF connected between CG+ and CG-, a typical AGC loop time constant of 760µs is achieved.
- Note 11: SD deassert time depends on the AGC loop time constant set by CcG.
- Note 12: SD accuracy is defined as the part-to-part variation of the SD threshold at a fixed R_{TH} value.
- Note 13: See the Distribution of SD Hysteresis (Worst-Case Conditions) graph in the Typical Operating Characteristics.
- Note 14: Measurements are taken over an input signal range of 20dB.

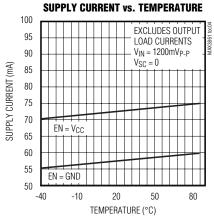
Typical Operating Characteristics

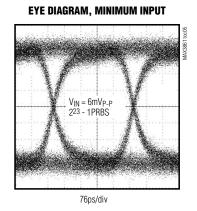
 $(V_{CC} = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$

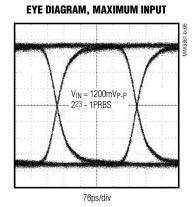








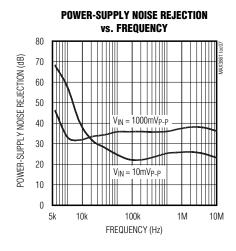


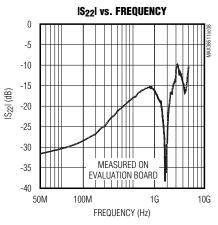


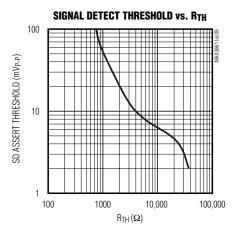
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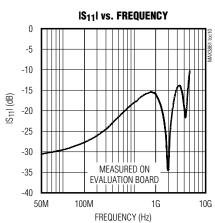
Typical Operating Characteristics (continued)

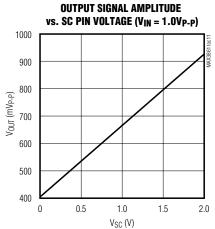
(V_{CC} = +3.3V, T_A = +25 $^{\circ}C$, unless otherwise noted.)

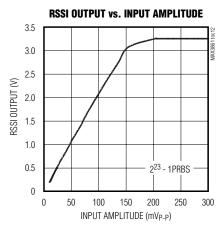


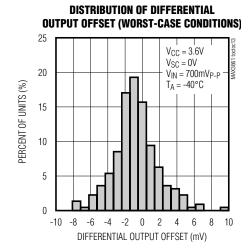


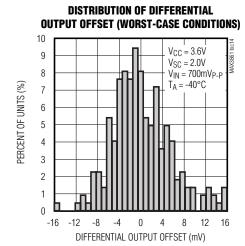












_____Pin Description

PIN	NAME	FUNCTION							
1	TH	Input Signal Detect Threshold Programming Pin. Attach a resistor between this pin and ground to program the input signal detect assert threshold. Leaving this pin open sets the signal detect threshold to its absolute minimum value (<2mV _{P-P}). See the <i>Design Procedure</i> section.							
2, 5, 14, 17	V _C C	Supply Voltage Connection. Connect all V _{CC} pins to the board V _{CC} plane.							
3	IN+	Positive CML Signal Input with On-Chip Termination Resistor							
4	IN-	Negative CML Signal Input with On-Chip Termination Resistor							
6	EN	Signal Detect Enable. Set high (≥2.0V) or leave open to enable the input signal detection (RSSI and SD) circuitry. Set low (≤0.4V) to power down the input signal detection circuitry.							
7	V _{REF}	Reference Voltage Output (2.0V). Connect this pin to the SC pin for maximum output signal swing.							
8	SC	Output Amplitude External Control. Ground SC for minimum output amplitude. Apply 2.0V to SC or connect SC directly to V _{REF} for maximum output amplitude.							
9, 12, 22	GND	Ground. Connect all GND pins to the board ground plane.							
10	CG+	Connection for AGC Loop Capacitor. A capacitor connected between CG+ and CG- sets the AGC loop time constant.							
11	CG-	Connection for AGC Loop Capacitor. A capacitor connected between CG+ and CG- sets the AGC loop time constant.							
13	OSM	Output Signal Monitor. This DC signal is linearly proportional to the output signal amplitude.							
15	OUT-	Negative CML Data Output with On-Chip Back-Termination Resistor							
16	OUT+	Positive CML Data Output with On-Chip Back-Termination Resistor							
18	SD	Input Signal Detect. Asserts logic low when the input signal level drops below the programmed threshold.							
19	RSSI	Received Signal Strength Indicator. Outputs a DC signal linearly proportional to the input signal amplitude.							
20	CD-	Connection for Signal Detect Capacitor. A capacitor connected between CD+ and CD- sets the offset-cancellation loop time constant of the input signal detection. See the <i>Detailed Description</i> section.							
21	CD+	Connection for Signal Detect Capacitor. A capacitor connected between CD+ and CD- sets the offset-cancellation loop time constant of the input signal detection. See the <i>Detailed Description</i> section.							
23	CZ-	Connection for Offset-Cancellation Loop Capacitor. A capacitor connected between CZ+ and CZ-sets the offset-cancellation loop time constant of the main signal path. See the <i>Detailed Description</i> section.							
24	CZ+	Connection for Offset-Cancellation Loop Capacitor. A capacitor connected between CZ+ and CZ-sets the offset-cancellation loop time constant of the main signal path. See the <i>Detailed Description</i> section.							
EP	Exposed Pad	Maxim recommends connecting the exposed pad to board ground.							

Detailed Description

Figure 1 is a functional diagram of the MAX3861 automatic gain-control amplifier. The MAX3861 is divided into three sections: main signal path, input signal detection, and output signal detection.

Main Signal Path

The main signal path consists of variable gain amplifiers with CML output levels and an offset-cancellation loop. This configuration allows for overall gains from -9.5dB to 43.5dB.

Offset-Cancellation Loop

The offset-cancellation loop partially reduces additional offset at the input. In communications systems using NRZ data with a 50% duty cycle, pulse-width distortion present in the signal or generated by the transimpedance amplifier appears as input offset and is partially removed by the offset-cancellation loop. An external capacitor is required between CZ+ and CZ- to compensate the offset-cancellation loop and determine the lower 3dB frequency of the signal path.

Input Signal Detection and SD Circuitry

The input signal detection circuitry consists of variable gain amplifiers and threshold voltages. Input signal detection information is compared to an internal reference and creates the RSSI voltage and an internal reference signal. The signal detect (SD) circuitry indicates when the input signal is below the programmed threshold by comparing a voltage proportional to the RSSI signal with internally generated control voltages. The SD threshold is set by a control voltage developed across the external TH resistor (RTH). Two control voltages, VASSERT and VDEASSERT, define the signal detect assert and deassert levels. To prevent SD chatter in the region of the programmed threshold, 2.8dB to 6.3dB of hysteresis is built into the SD assert/deassert function. Thus, once asserted, SD is not deasserted until sufficient gain is retained. When input signal detection (SD and RSSI) is not required, connect EN to a TTL low to power down this circuitry.

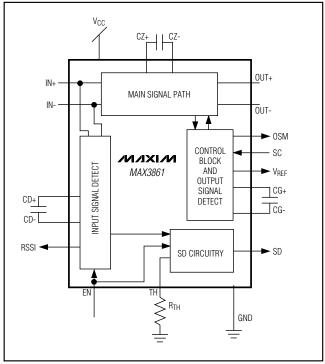


Figure 1. Functional Diagram

Output Signal Monitor and Amplitude Control

Output amplitude typically can be adjusted from 400mV_{P-P} to 920mV_{P-P} by applying a control voltage (0V to 2.0V) to the SC pin. See the Output Signal Amplitude vs. SC Pin Voltage graph in the *Typical Operating Characteristics*. Connect the V_{REF} pin (2.0V) to the SC pin for maximum output amplitude. The output signal monitor pin provides a DC voltage linearly proportional to the output signal.

Design Procedure

Program the SD Threshold

The SD threshold is programmed by an external resistor, R_{TH}, between the range of 2mV_{P-P} to 100mV_{P-P}. The circuit is designed to have approximately 4.5dB of hysteresis over the full range. See the Signal Detect Threshold vs. R_{TH} graph in the *Typical Operating Characteristics* for proper sizing.

Select the Coupling Capacitors

When AC-coupling is desired, select coupling capacitors C_{IN} and C_{OUT} to minimize the receiver's deterministic jitter. Jitter is decreased as the input low-frequency cutoff (f_{IN}) is decreased.

$$f_{IN} = \frac{1}{\left[2\pi(50)(C_{IN})\right]}$$

For ATM/SONET or other applications using scrambled NRZ data, select (C_{IN} , C_{OUT}) \geq 0.1 μ F, which provides f_{IN} < 32kHz. For Fibre Channel, Gigabit Ethernet, and other applications using 8B/10B data coding, select (C_{IN} , C_{OUT}) \geq 0.01 μ F, which provides f_{IN} < 320kHz.

Setting the Offset-Cancellation Loop Time Constant for Input Signal Detection Circuitry (Selecting CCD)

The capacitor between CD+ and CD- determines the time constant of the input signal detection DC offset-cancellation loop. A value of $0.1\mu F$ for C_{CD} provides a low-frequency cutoff (f_C) below 10kHz. If a lower cutoff frequency is desired, $0.22\mu F$ gives f_C = 4.5kHz and $0.47\mu F$ gives f_C = 2.1kHz. To guarantee stable operation, do not use a capacitor of less than $0.01\mu F$.

Setting the Offset-Cancellation Loop Time Constant for the Main Signal Path (Selecting Ccz)

The capacitor between CZ+ and CZ- determines the time constant of the signal path DC offset-cancellation loop. To maintain stability, keep a one-decade separation between flN and the low-frequency cutoff (foc) associated with the DC offset-cancellation circuit. For SONET applications, flN < 32kHz, so focmax < 3.2kHz. Therefore, Ccz = 0.22µF (foc = 2.99kHz), Ccz = 0.47µF (foc = 1.4kHz), or a greater value can be used. To guarantee stable operation, do not use a capacitor of less than 0.01µF.

Setting the Automatic Gain-Control Loop Time Constant (Selecting Ccg)

The automatic gain-control loop time constant is determined by the external capacitor connected between CG+ and CG-. Maxim recommends a value of at least $0.0022\mu F$.

Programming the Output Amplitude (Programming the SC Pin)

Output amplitude can be programmed from 400mV_{P-P} to 920mV_{P-P} by applying a voltage to the SC pin. See the Output Signal Amplitude vs. SC Pin Voltage graph in the *Typical Operating Characteristics*.

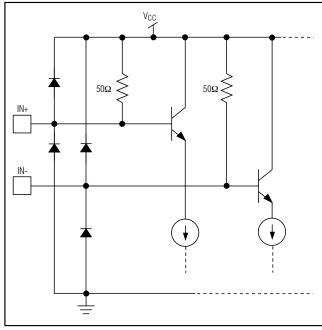


Figure 2. Input Interface

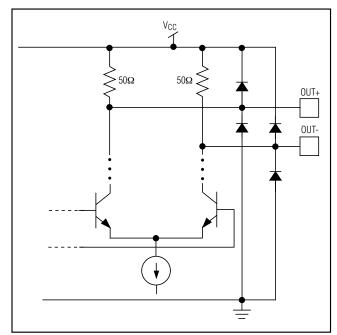


Figure 3. Output Interface

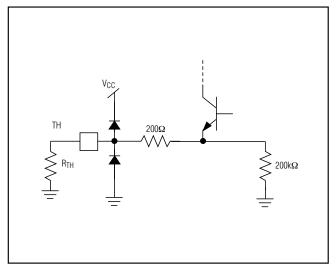


Figure 4. TH Interface

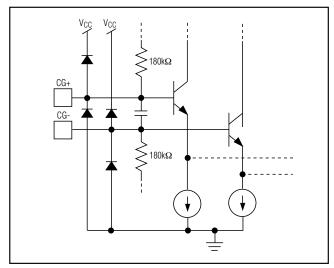


Figure 5. CG Interface

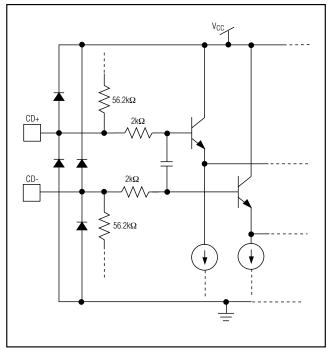


Figure 6. CD Interface

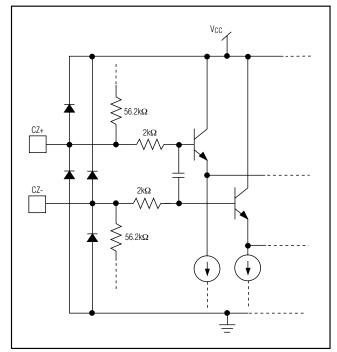
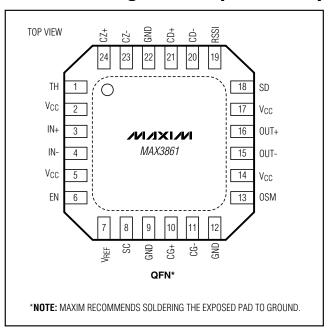


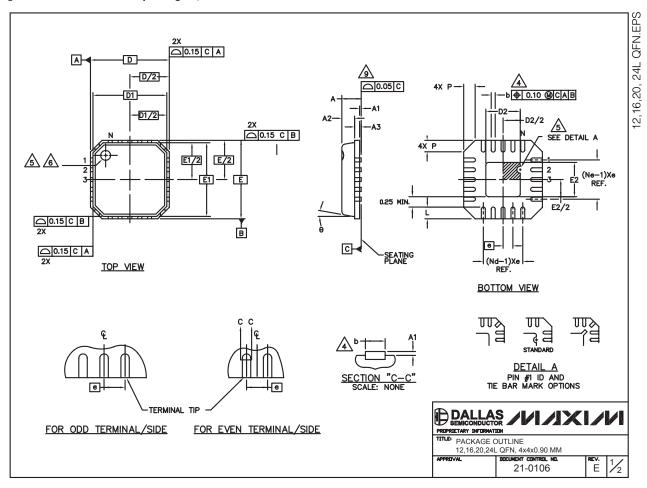
Figure 7. CZ Interface

Pin Configurations (continued)



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

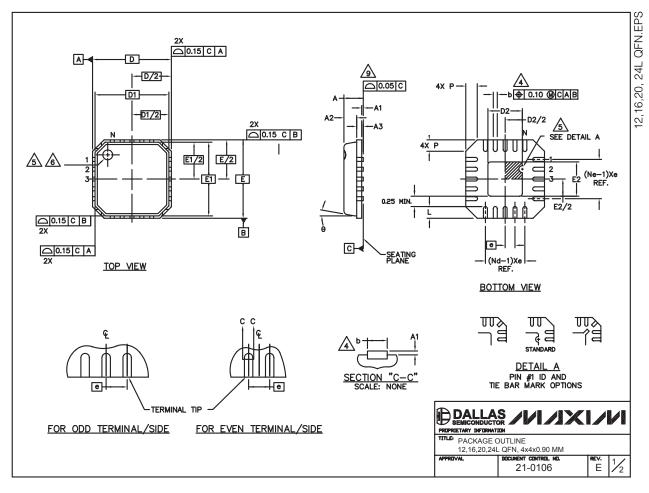


Chip Information

TRANSISTOR COUNT: 952 PROCESS: SiGe Bipolar

Package Information (continued)

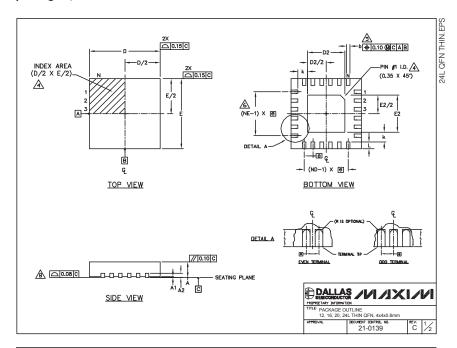
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



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Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



COMMON DIMENSIONS												
PKG	12L 4×4			16L 4×4			20L 4×4			24L 4×4		
REF.	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.	MIN	NDM.	MAX.	MIN.	NDM.	MAX
Α	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.8
AL	0.0	0.02	0.05	0.0	0.02	0.05	0.0	20.0	0.05	0.0	0.02	0.0
A2	0	.20 RE	F	0.20 REF			0.20 REF			0.20 REF		
b	0.25	0.30	0.35	0.25	0.30	0,35	0.20	0.25	0.30	0.18	0.23	0.3
D	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10	3.90	4.00	4.10
E	3,90	4.00	4,10	3.90	4.00	4.10	3.90	4.00	4.10	3,90	4.00	4.10
6	(.80 BS	C.	0.65 BSC.		0.50 BSC.			0.50 BSC.			
k	0.25	-	-	0.25	-	-	0.25	-	ı	0.25	-	-
L	0.45	0.55	0.65	0.45	0.55	0.65	0.45	0.55	0.65	0.30	0.40	0.5
N	12			16			20 5			24 6		
ND	3		4									
NE	3		4		5			6				
Jedec Var.	WGGB		WGGC		VGGD-1			WGGD-2				

l E	XPUS	SED.	VARIATIONS				
PKG.		DS			DOWN		
CODES	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.	ALLOVED
T1244-2	1.95	2.10	2.25	1.95	2.10	2.25	ND
T1244-3	1.95	2.10	2,25	1.95	2.10	2,25	YES
T1244-4	1.95	2.10	2.25	1.95	2.10	2.25	ND
T1644-2	1.95	2.10	2,25	1.95	2.10	2,25	ND
T1644-3	1.95	2.10	2.25	1.95	2.10	2.25	YES
T1644-4	1.95	2.10	2.25	1.95	2.10	2,25	NO
T2044-1	1.95	2.10	2.25	1.95	2.10	2.25	NO
T2044-2	1.95	2.10	2.25	1.95	2.10	2,25	YES
T2044-3	1.95	2.10	2.25	1.95	2.10	2.25	ND
T2444-1	2.45	2.60	2.63	2.45	2.60	2.63	ND
T2444-2	1.95	2.10	2.25	1.95	2.10	2.25	YES
T2444-3	2.45	2.60	2.63	2.45	2.60	2.63	YES
T2444-4	2.45	2.60	2.63	2.45	2.60	2.63	NO

- 1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14,5M-1994.
- ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES. N IS THE TOTAL NUMBER OF TERMINALS.
- THE TERMINAL \$1 IDENTIFIER AND TERMINAL MUMBERING CONVENTION SHALL CONFORM TO JEED 95-1 SPP-012 LOCATED, WITHIN 1918 THE ZONE INDICATED, LOCATED WITHIN EACH PROPERTY OF MICHAEL SHALL SHA
- DIMENSION 6 APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.25 mm AND 0.30 mm FROM TERMINAL TIP.
- ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY, DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
- COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
- NG CONFORMS TO JEDEC MO220, EXCEPT FOR T2444-1, T2444-3 AND T2444-4.

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